MT4953

P-Channel Enhancement Mode Field Effect Transistor

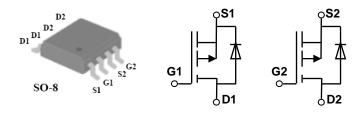
FEATURES

- Super high dense cell design for low RDS(ON)
- Rugged and reliable
- Simple drive requirement
- SOP-8 package

PRODUCT	SUMMARY	
Vdss	Id	$RDS(ON) (m \Omega) Typ$
2014	-5.3A	46@ VGS=-10V
-30V		78 @ VGS=-4.5V



NOTE: The MT4953 is available in a lead-free package



ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-30	v
Gate-Source Voltage	VGS	±20	V
Drain Current-Continuous ^a @Tj=125°C	ID	-5.3	А
- Pulse d^b	Ідм	-24	А
Drain-source Diode Forward Current ^a	Is	-1.7	А
Maximum Power Dissipation ^a	Pd	2.5	W
Operating Junction and Storage Temperature Range	Тј,Тѕтб	-55 to 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to Ambient ^a Rth JA50°C/W



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ELECTRICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
OFF CHARACTERISTICS			•	•	•	
Drain-Source Breakdown Voltage	BVDSS	Vgs=0V,Id=-250µA	-30			V
Zero Gate Voltage Drain Current	IDSS	Vds=-24V,Vgs=0V			-1	μA
Gate-Body Leakage	IGSS	Vgs=±20V,Vds=0V			±100	nA
ON CHARACTERITICS						
Gate Threshold Voltage	VGs(th)	VDS=VGS,ID=-250µA	-1	-1.5	-2.5	V
	Deserve	Vgs=-10V,Id=-5.3A		46	55	
Drain-Source On-State Resistance	RDS(ON)	Vgs=-4.5V,Id=-4.2A	78			mΩ
Forward Transconductance	gFS	VGS=-5V,ID=-5.3A		5		S
DAYNAMIC CHARACTERISTICS			-	•	•	
Input Capacitance	Ciss			582		pF
Output Capacitance	Coss	VDS=-15V,VGS=0V f=1.0MHz		125		pF
Reverse Transfer Capacitance	Crss	1-1.0101112		86		pF
SWITCHING CHARACTERISISTICS	1 1			1		
Turn-On Delay Time	td(on)	VDD=-15V		9		ns
Rise Time	tr	ID=-5.3A,		10		ns
Turn-Off Delay Time	tD(OFF)	VGEN=-4.5V RL=100hm		38		ns
Fall Time	tf	RGEN=10ohm		23		ns
Total Gate Charge	Qg			11.7		nC
Gate-Source Charge	Qgs	VDS=-15V,ID=-1A		2.1		nC
Gate-Drain Charge	Qgd	VGS=-10V		2.9		nC



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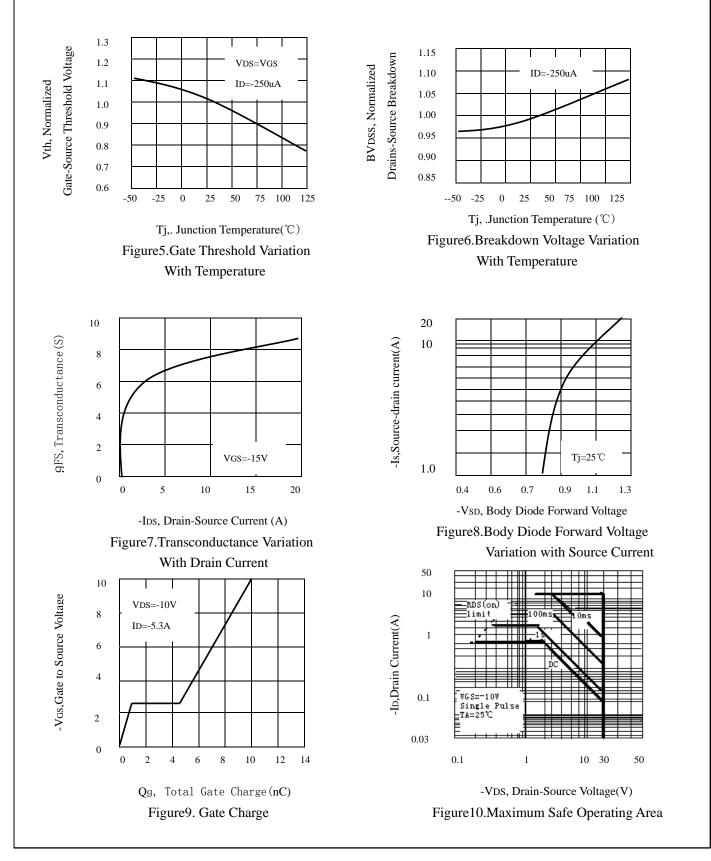
Parameter	eter Symbol Condi		ndition	Min	Тур	Max	Uni
DRAIN-SOURCE DIODE CHARACT	TERISTICS			L	1		I
Diode Forward Voltage	Vsd	V _G s=0	V,Is=-1.7A		-0.84	-1.2	v
Totes Surface Mounted on FR4 Board, t \leq Pulse Test: Pulse Width \leq 300Us, D Guaranteed by design, not subject to 25 20 15 10 10 10 2 10 2 10 2 10 2 10 2 10 2 10 2 10 2 2 4 6 Figure 1. Output Ch	ty Cycle ≤ 2% production testing .6, V 	-ID,Drain Current(A)		125℃ → 25℃ 8 1.6 2 Gate-to-sc Transfer C			(V)
CCCapacitance(PF) 0 0 0 0 0 0 0 0 0 0	Ciss Coss Coss 15 20 25	RDS(ON), On-Resistance(mΩ)	1.0	VGS=-10V D=-5.6A	5 50	75 100 Tj (125

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